

# ADG774\* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

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## DOCUMENTATION

### Application Notes

- AN-1024: How to Calculate the Settling Time and Sampling Rate of a Multiplexer

### Data Sheet

- ADG774: CMOS 3 V/5 V, Wide Bandwidth Quad 2:1 Mux Data Sheet

## REFERENCE MATERIALS

### Product Selection Guide

- Switches and Multiplexers Product Selection Guide

### Technical Articles

- CMOS Switches Offer High Performance in Low Power, Wideband Applications
- Data-acquisition system uses fault protection
- Enhanced Multiplexing for MEMS Optical Cross Connects
- Temperature monitor measures three thermal zones

## DESIGN RESOURCES

- ADG774 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

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# ADG774—SPECIFICATIONS

**SINGLE SUPPLY** ( $V_{DD} = 5\text{ V} \pm 10\%$ ,  $GND = 0\text{ V}$ . All specifications  $T_{MIN}$  to  $T_{MAX}$  unless otherwise noted.)

| Parameter                                                | B Version <sup>1</sup> |       |                        | Unit    | Test Conditions/Comments                                                                                   |
|----------------------------------------------------------|------------------------|-------|------------------------|---------|------------------------------------------------------------------------------------------------------------|
|                                                          | +25°C                  | +85°C | +125°C                 |         |                                                                                                            |
| ANALOG SWITCH                                            |                        |       |                        |         |                                                                                                            |
| Analog Signal Range                                      |                        |       | 0 V to V <sub>DD</sub> | V       | V <sub>D</sub> = 0 V to V <sub>DD</sub> , I <sub>S</sub> = −10 mA                                          |
| On Resistance (R <sub>ON</sub> )                         | 2.2                    |       |                        | Ω typ   |                                                                                                            |
|                                                          |                        | 5     | 7                      | Ω max   |                                                                                                            |
| On Resistance Match between Channels (ΔR <sub>ON</sub> ) | 0.15                   |       |                        | Ω typ   | V <sub>D</sub> = 0 V to V <sub>DD</sub> , I <sub>S</sub> = −10 mA                                          |
|                                                          |                        | 0.5   | 0.5                    | Ω max   |                                                                                                            |
| On Resistance Flatness (R <sub>FLAT(ON)</sub> )          | 0.5                    |       |                        | Ω typ   | V <sub>D</sub> = 0 V to V <sub>DD</sub> , I <sub>S</sub> = −1 mA                                           |
|                                                          |                        | 1     | 1                      | Ω max   |                                                                                                            |
| LEAKAGE CURRENTS                                         |                        |       |                        |         |                                                                                                            |
| Source OFF Leakage I <sub>S</sub> (OFF)                  | ±0.01                  |       |                        | nA typ  | V <sub>D</sub> = 4.5 V, V <sub>S</sub> = 1 V; V <sub>D</sub> = 1 V, V <sub>S</sub> = 4.5 V; Test Circuit 2 |
|                                                          | ±0.5                   | ±1    | ±1.5                   | nA max  |                                                                                                            |
| Drain OFF Leakage I <sub>D</sub> (OFF)                   | ±0.01                  |       |                        | nA typ  | V <sub>D</sub> = 4.5 V, V <sub>S</sub> = 1 V; V <sub>D</sub> = 1 V, V <sub>S</sub> = 4.5 V; Test Circuit 2 |
|                                                          | ±0.5                   | ±1    | ±1.5                   | nA max  |                                                                                                            |
| Channel ON Leakage I <sub>D</sub> , I <sub>S</sub> (ON)  | ±0.01                  |       |                        | nA typ  | V <sub>D</sub> = V <sub>S</sub> = 4.5 V; V <sub>D</sub> = V <sub>S</sub> = 1 V; Test Circuit 3             |
|                                                          | ±0.5                   | ±1    | ±1.5                   | nA max  |                                                                                                            |
| DIGITAL INPUTS                                           |                        |       |                        |         |                                                                                                            |
| Input High Voltage, V <sub>INH</sub>                     |                        |       | 2.0                    | V min   | V <sub>IN</sub> = V <sub>INL</sub> or V <sub>INH</sub>                                                     |
| Input Low Voltage, V <sub>INL</sub>                      |                        |       | 0.8                    | V max   |                                                                                                            |
| Input Current                                            |                        |       |                        |         |                                                                                                            |
| I <sub>INL</sub> or I <sub>INH</sub>                     | 0.001                  |       |                        | μA typ  |                                                                                                            |
|                                                          |                        |       | ±0.5                   | μA max  |                                                                                                            |
| DYNAMIC CHARACTERISTICS <sup>2</sup>                     |                        |       |                        |         |                                                                                                            |
| t <sub>ON</sub>                                          |                        | 7     |                        | ns typ  | R <sub>L</sub> = 100 Ω, C <sub>L</sub> = 35 pF, V <sub>S</sub> = +3 V; Test Circuit 4                      |
|                                                          |                        | 15    | 20                     | ns max  |                                                                                                            |
| t <sub>OFF</sub>                                         |                        | 4     |                        | ns typ  | R <sub>L</sub> = 100 Ω, C <sub>L</sub> = 35 pF, V <sub>S</sub> = +3 V; Test Circuit 4                      |
|                                                          |                        | 8     | 9                      | ns max  |                                                                                                            |
| Break-Before-Make Time Delay, t <sub>D</sub>             |                        | 5     |                        | ns typ  | R <sub>L</sub> = 100 Ω, C <sub>L</sub> = 35 pF, V <sub>S1</sub> = V <sub>S2</sub> = +5 V; Test Circuit 5   |
|                                                          |                        | 1     |                        | ns min  |                                                                                                            |
| Off Isolation                                            |                        | −65   |                        | dB typ  | R <sub>L</sub> = 100 Ω, f = 10 MHz; Test Circuit 7                                                         |
| Channel-to-Channel Crosstalk                             |                        | −75   |                        | dB typ  | R <sub>L</sub> = 100 Ω, f = 10 MHz; Test Circuit 8                                                         |
| Bandwidth −3 dB                                          |                        | 240   |                        | MHz typ | R <sub>L</sub> = 100 Ω; Test Circuit 6                                                                     |
| Distortion                                               |                        | 0.5   |                        | % typ   | R <sub>L</sub> = 100 Ω                                                                                     |
| Charge Injection                                         |                        | 10    |                        | pC typ  | C <sub>L</sub> = 1 nF; Test Circuit 9                                                                      |
| C <sub>S</sub> (OFF)                                     |                        | 10    |                        | pF typ  | f = 1 kHz                                                                                                  |
| C <sub>D</sub> (OFF)                                     |                        | 20    |                        | pF typ  | f = 1 kHz                                                                                                  |
| C <sub>D</sub> , C <sub>S</sub> (ON)                     |                        | 30    |                        | pF typ  | f = 1 MHz                                                                                                  |
| POWER REQUIREMENTS                                       |                        |       |                        |         |                                                                                                            |
| I <sub>DD</sub>                                          |                        | 1     | 1                      | μA max  | V <sub>DD</sub> = +5.5 V<br>Digital Inputs = 0 V or V <sub>DD</sub>                                        |
|                                                          | 0.001                  |       |                        | μA typ  |                                                                                                            |
| I <sub>IN</sub>                                          |                        | 1     | 1                      | μA typ  | V <sub>IN</sub> = +5 V<br>V <sub>S</sub> /V <sub>D</sub> = 0 V                                             |
| I <sub>O</sub>                                           |                        | 100   |                        | mA max  |                                                                                                            |

## NOTES

<sup>1</sup>Temperature range: B Version, -40°C to +125°C.

<sup>2</sup>Guaranteed by design, not subject to production test.

Specifications subject to change without notice.

**SINGLE SUPPLY** ( $V_{DD} = 3\text{ V} \pm 10\%$ ,  $GND = 0\text{ V}$ . All specifications  $T_{MIN}$  to  $T_{MAX}$  unless otherwise noted.)

| Parameter                                                | B Version <sup>1</sup> |       |                        | Unit             | Test Conditions/Comments                                                                                   |
|----------------------------------------------------------|------------------------|-------|------------------------|------------------|------------------------------------------------------------------------------------------------------------|
|                                                          | +25°C                  | +85°C | +125°C                 |                  |                                                                                                            |
| ANALOG SWITCH                                            |                        |       |                        |                  |                                                                                                            |
| Analog Signal Range                                      | 4                      |       | 0 V to V <sub>DD</sub> | V                | V <sub>D</sub> = 0 V to V <sub>DD</sub> , I <sub>S</sub> = −10 mA                                          |
| On Resistance (R <sub>ON</sub> )                         |                        | 8     | 9                      | Ω typ<br>Ω max   |                                                                                                            |
| On Resistance Match between Channels (ΔR <sub>ON</sub> ) | 0.15                   |       |                        | Ω typ<br>Ω max   | V <sub>D</sub> = 0 V to V <sub>DD</sub> , I <sub>S</sub> = −10 mA                                          |
| On Resistance Flatness (R <sub>FLAT(ON)</sub> )          | 2                      | 0.5   | 0.5                    | Ω typ<br>Ω max   | V <sub>D</sub> = 0 V to V <sub>DD</sub> , I <sub>S</sub> = −10 mA                                          |
|                                                          |                        | 4     | 4                      | Ω max            |                                                                                                            |
| LEAKAGE CURRENTS                                         |                        |       |                        |                  |                                                                                                            |
| Source OFF Leakage I <sub>S</sub> (OFF)                  | ±0.01<br>±0.5          | ±1    | ±1.5                   | nA typ<br>nA max | V <sub>D</sub> = 3 V, V <sub>S</sub> = 1 V; V <sub>D</sub> = 1 V, V <sub>S</sub> = 3 V;<br>Test Circuit 2  |
| Drain OFF Leakage I <sub>D</sub> (OFF)                   | ±0.01<br>±0.5          |       |                        | nA typ<br>nA max | V <sub>D</sub> = 3 V, V <sub>S</sub> = 1 V; V <sub>D</sub> = 1 V, V <sub>S</sub> = 3 V;<br>Test Circuit 2  |
| Channel ON Leakage I <sub>D</sub> , I <sub>S</sub> (ON)  | ±0.01<br>±0.5          | ±1    | ±1.5                   | nA typ<br>nA max | V <sub>D</sub> = V <sub>S</sub> = 3 V; V <sub>D</sub> = V <sub>S</sub> = 1 V; Test Circuit 3               |
| DIGITAL INPUTS                                           |                        |       |                        |                  |                                                                                                            |
| Input High Voltage, V <sub>INH</sub>                     |                        |       | 2.0                    | V min            | V <sub>IN</sub> = V <sub>INL</sub> or V <sub>INH</sub>                                                     |
| Input Low Voltage, V <sub>INL</sub>                      |                        |       | 0.8                    | V max            |                                                                                                            |
| Input Current                                            | 0.001                  |       |                        | μA typ           |                                                                                                            |
| I <sub>INL</sub> or I <sub>INH</sub>                     |                        |       | ±0.5                   | μA max           |                                                                                                            |
| DYNAMIC CHARACTERISTICS <sup>2</sup>                     |                        |       |                        |                  |                                                                                                            |
| t <sub>ON</sub>                                          | 8                      |       |                        | ns typ           | R <sub>L</sub> = 100 Ω, C <sub>L</sub> = 35 pF,<br>V <sub>S</sub> = +1.5 V; Test Circuit 4                 |
|                                                          | 16                     | 21    |                        | ns max           |                                                                                                            |
| t <sub>OFF</sub>                                         | 5                      |       |                        | ns typ           | R <sub>L</sub> = 100 Ω, C <sub>L</sub> = 35 pF,<br>V <sub>S</sub> = +1.5 V; Test Circuit 4                 |
|                                                          | 10                     | 11    |                        | ns max           |                                                                                                            |
| Break-Before-Make Time Delay, t <sub>D</sub>             | 5                      |       |                        | ns typ           | R <sub>L</sub> = 100 Ω, C <sub>L</sub> = 35 pF,<br>V <sub>S1</sub> = V <sub>S2</sub> = 3 V; Test Circuit 5 |
|                                                          | 1                      |       |                        | ns min           |                                                                                                            |
| Off Isolation                                            | −65                    |       |                        | dB typ           | R <sub>L</sub> = 50 Ω, f = 10 MHz; Test Circuit 7                                                          |
| Channel-to-Channel Crosstalk                             | −75                    |       |                        | dB typ           |                                                                                                            |
| Bandwidth −3 dB                                          | 240                    |       |                        | MHz typ          | R <sub>L</sub> = 50 Ω; Test Circuit 8                                                                      |
| Distortion                                               | 2                      |       |                        | % typ            | R <sub>L</sub> = 50 Ω; Test Circuit 6                                                                      |
| Charge Injection                                         | 3                      |       |                        | pC typ           | C <sub>L</sub> = 1 nF; Test Circuit 9                                                                      |
| C <sub>S</sub> (OFF)                                     | 10                     |       |                        | pF typ           |                                                                                                            |
| C <sub>D</sub> (OFF)                                     | 20                     |       |                        | pF typ           | f = 1 kHz                                                                                                  |
| C <sub>D</sub> , C <sub>S</sub> (ON)                     | 30                     |       |                        | pF typ           | f = 1 MHz                                                                                                  |
| POWER REQUIREMENTS                                       |                        |       |                        |                  |                                                                                                            |
| I <sub>DD</sub>                                          | 0.001                  | 1     | 1                      | μA max<br>μA typ | V <sub>DD</sub> = +3.3 V<br>Digital Inputs = 0 V or V <sub>DD</sub>                                        |
| I <sub>IN</sub>                                          |                        | 1     | 1                      | μA typ           | V <sub>IN</sub> = +3 V                                                                                     |
| I <sub>O</sub>                                           |                        | 100   |                        | mA max           | V <sub>S</sub> /V <sub>D</sub> = 0 V                                                                       |

## NOTES

<sup>1</sup>Temperature range: B Version, -40°C to +125°C.<sup>2</sup>Guaranteed by design, not subject to production test.

Specifications subject to change without notice.

Table I. Truth Table

| $\overline{EN}$ | IN | D1   | D2   | D3   | D4   | Function |
|-----------------|----|------|------|------|------|----------|
| 1               | X  | Hi-Z | Hi-Z | Hi-Z | Hi-Z | DISABLE  |
| 0               | 0  | S1A  | S2A  | S3A  | S4A  | IN = 0   |
| 0               | 1  | S1B  | S2B  | S3B  | S4B  | IN = 1   |

# ADG774

## ABSOLUTE MAXIMUM RATINGS<sup>1</sup>

(T<sub>A</sub> = 25°C unless otherwise noted.)

|                                     |                                                                       |
|-------------------------------------|-----------------------------------------------------------------------|
| V <sub>DD</sub> to GND              | −0.3 V to +6 V                                                        |
| Analog, Digital Inputs <sup>2</sup> | −0.3 V to V <sub>DD</sub> + 0.3 V or<br>30 mA, Whichever Occurs First |
| Continuous Current, S or D          | 100 mA                                                                |
| Peak Current, S or D                | 300 mA<br>(Pulsed at 1 ms, 10% Duty Cycle max)                        |
| Operating Temperature Range         |                                                                       |
| Industrial (B Version)              | −40°C to +125°C                                                       |
| Storage Temperature Range           | −65°C to +150°C                                                       |
| Junction Temperature                | 150°C                                                                 |
| SOIC Package, Power Dissipation     | 600 mW                                                                |
| θ <sub>JA</sub> Thermal Impedance   | 100°C/W                                                               |

|                                        |            |
|----------------------------------------|------------|
| QSOP Package, Power Dissipation        | 566 mW     |
| θ <sub>JA</sub> Thermal Impedance      | 149.97°C/W |
| Lead Temperature, Soldering (10 sec)   | 300°C      |
| I R Reflow, Peak Temperature (<20 sec) | 235°C      |
| ESD                                    | 2 kV       |

## NOTES

<sup>1</sup>Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Only one absolute maximum rating may be applied at any one time.

<sup>2</sup>Overvoltages at IN, S, or D will be clamped by internal diodes. Current should be limited to the maximum ratings given.

## ORDERING GUIDE

| Model             | Temperature Range | Package Descriptions                  | Package Options |
|-------------------|-------------------|---------------------------------------|-----------------|
| ADG774BR          | −40°C to +125°C   | Standard Small Outline Package (SOIC) | R-16            |
| ADG774BR-REEL     | −40°C to +125°C   | Standard Small Outline Package (SOIC) | R-16            |
| ADG774BR-REEL7    | −40°C to +125°C   | Standard Small Outline Package (SOIC) | R-16            |
| ADG774BRZ*        | −40°C to +125°C   | Standard Small Outline Package (SOIC) | R-16            |
| ADG774BRZ-REEL*   | −40°C to +125°C   | Standard Small Outline Package (SOIC) | R-16            |
| ADG774BRZ-REEL7*  | −40°C to +125°C   | Standard Small Outline Package (SOIC) | R-16            |
| ADG774BRQ         | −40°C to +125°C   | Shrink Small Outline Package (QSOP)   | RQ-16           |
| ADG774BRQ-REEL    | −40°C to +125°C   | Shrink Small Outline Package (QSOP)   | RQ-16           |
| ADG774BRQ-REEL7   | −40°C to +125°C   | Shrink Small Outline Package (QSOP)   | RQ-16           |
| ADG774BRQZ*       | −40°C to +125°C   | Shrink Small Outline Package (QSOP)   | RQ-16           |
| ADG774BRQZ-REEL*  | −40°C to +125°C   | Shrink Small Outline Package (QSOP)   | RQ-16           |
| ADG774BRQZ-REEL7* | −40°C to +125°C   | Shrink Small Outline Package (QSOP)   | RQ-16           |

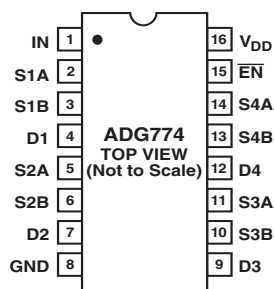
\*Z = Pb-free part.

## CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the ADG774 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



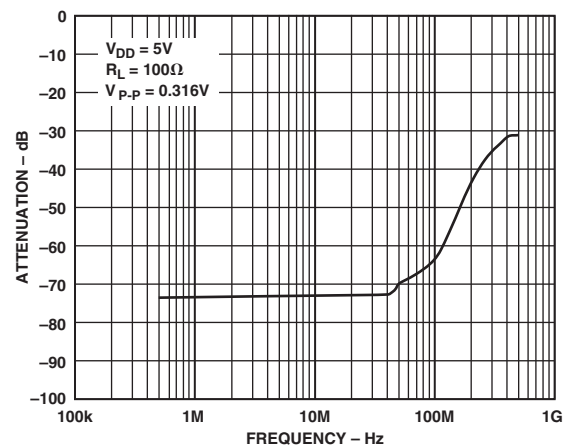
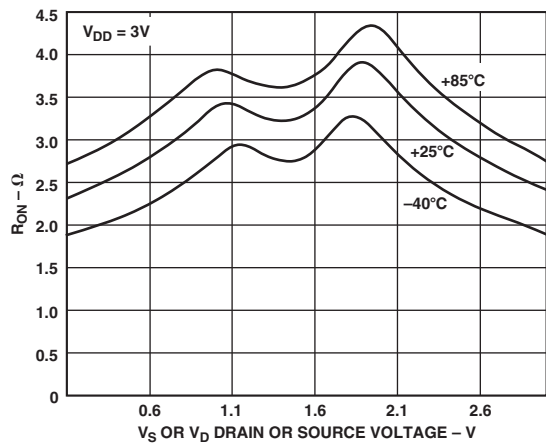
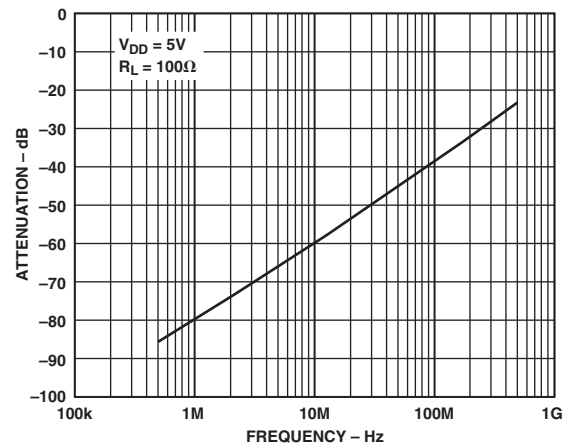
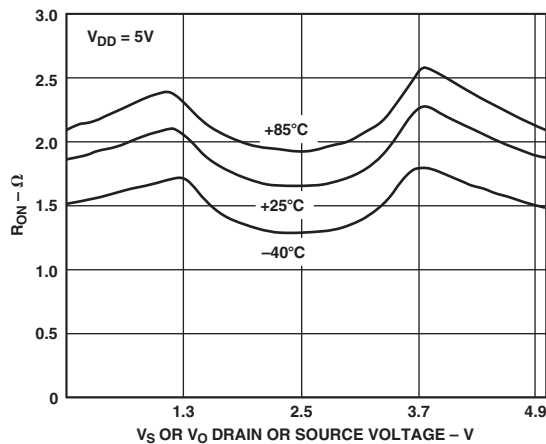
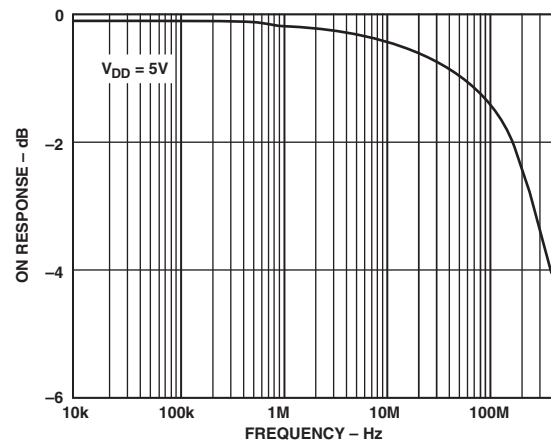
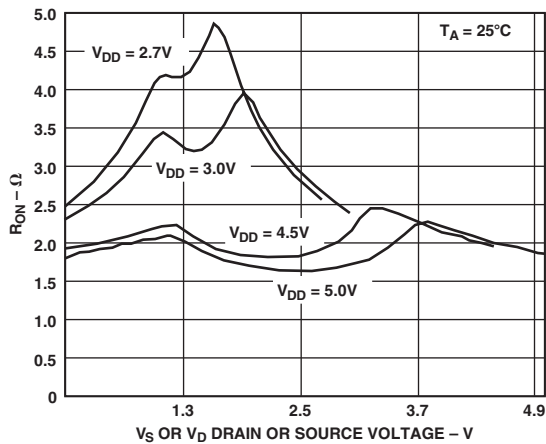
### PIN CONFIGURATION (SOIC/QSOP)

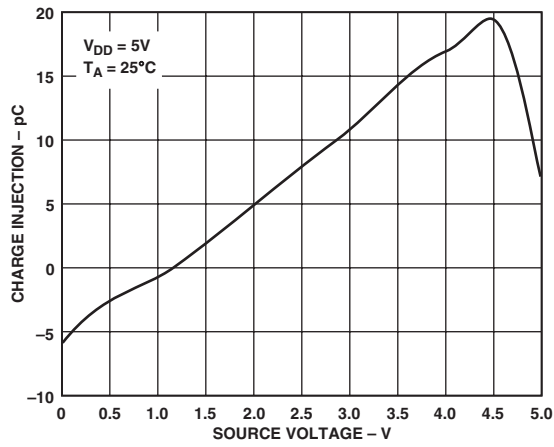


### TERMINOLOGY

|                 |                                                                                                                                                  |
|-----------------|--------------------------------------------------------------------------------------------------------------------------------------------------|
| $V_{DD}$        | Most Positive Power Supply Potential.                                                                                                            |
| GND             | Ground (0 V) Reference.                                                                                                                          |
| S               | Source Terminal. May be an input or output.                                                                                                      |
| D               | Drain Terminal. May be an input or output.                                                                                                       |
| IN              | Logic Control Input.                                                                                                                             |
| $\overline{EN}$ | Logic Control Input.                                                                                                                             |
| $R_{ON}$        | Ohmic Resistance between D and S.                                                                                                                |
| $\Delta R_{ON}$ | On Resistance Match between any Two Channels, i.e., $R_{ON\ max} - R_{ON\ min}$ .                                                                |
| $R_{FLAT(ON)}$  | Flatness is defined as the difference between the maximum and minimum value of on resistance as measured over the specified analog signal range. |
| $I_S$ (OFF)     | Source Leakage Current with the Switch OFF.                                                                                                      |
| $I_D$ (OFF)     | Drain Leakage Current with the Switch OFF.                                                                                                       |
| $I_D, I_S$ (ON) | Channel Leakage Current with the Switch ON.                                                                                                      |
| $V_D$ ( $V_S$ ) | Analog Voltage on Terminals D, S.                                                                                                                |
| $C_S$ (OFF)     | OFF Switch Source Capacitance.                                                                                                                   |
| $C_D$ (OFF)     | OFF Switch Drain Capacitance.                                                                                                                    |
| $C_D, C_S$ (ON) | ON Switch Capacitance.                                                                                                                           |
| $t_{ON}$        | Delay between Applying the Digital Control Input and the Output Switching on. See Test Circuit 4.                                                |
| $t_{OFF}$       | Delay between Applying the Digital Control Input and the Output Switching Off.                                                                   |
| $t_D$           | OFF Time or ON Time Measured between the 90% Points of Both Switches, When Switching from One Address State to Another. See Test Circuit 5.      |
| Crosstalk       | A Measure of Unwanted Signal that is Coupled through from One Channel to Another as a Result of Parasitic Capacitance.                           |
| Off Isolation   | A Measure of Unwanted Signal Coupling through an OFF Switch.                                                                                     |
| Bandwidth       | Frequency Response of the Switch in the ON State Measured at 3 dB Down.                                                                          |
| Distortion      | $R_{FLAT(ON)}/R_L$                                                                                                                               |

# ADG774—Typical Performance Characteristics





TPC 7. Charge Injection vs. Source Voltage

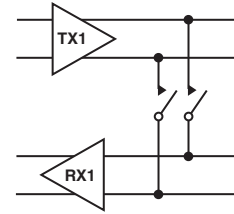


Figure 1. Loop Back

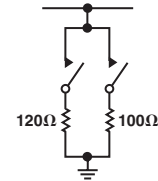


Figure 2. Line Termination

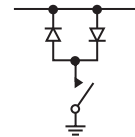
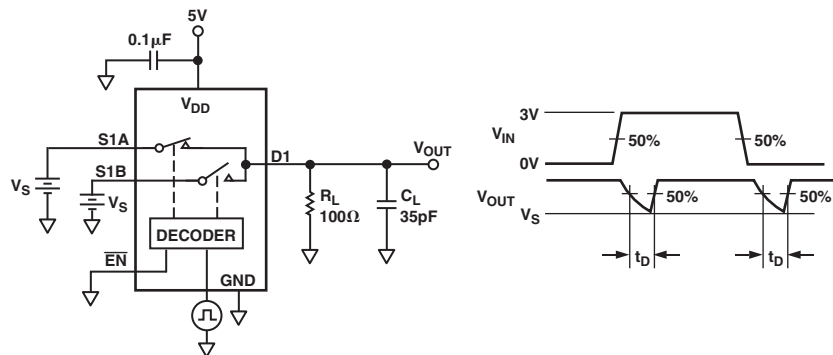
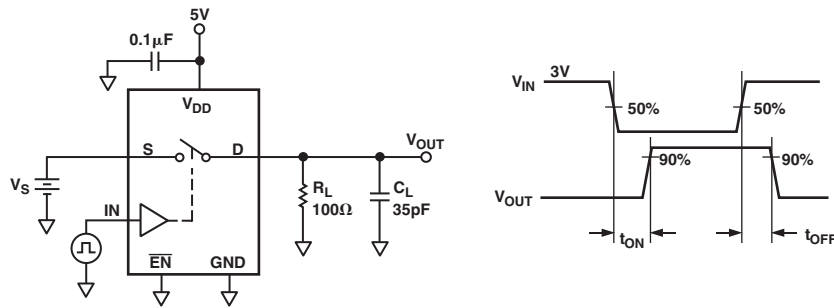
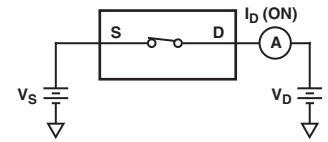
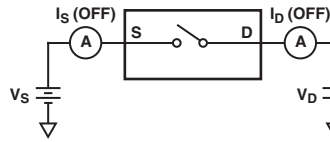
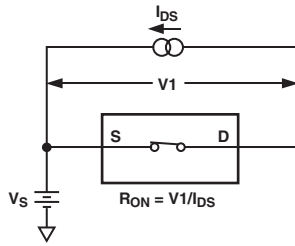


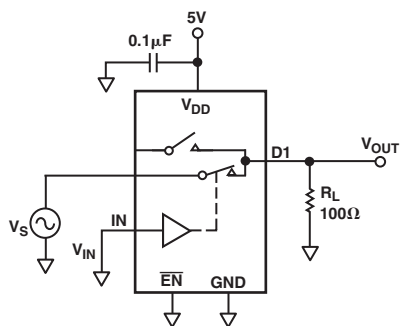
Figure 3. Line Clamp

# ADG774

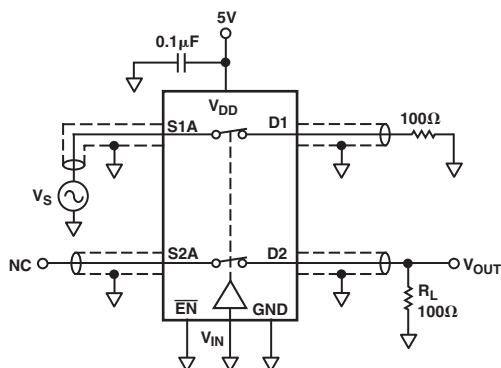
## Test Circuits





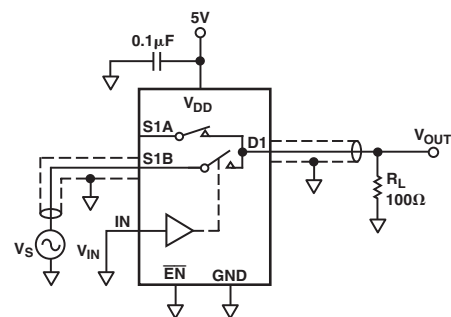


Test Circuit 6. Bandwidth

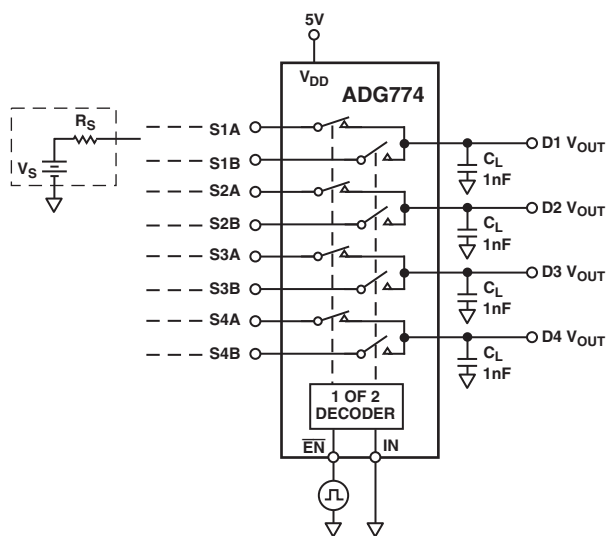


$$\text{CHANNEL-TO-CHANNEL CROSSTALK} = 20 \times \log |V_S/V_{OUT}|$$

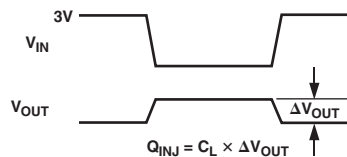
Test Circuit 7. Channel-to-Channel Crosstalk



Test Circuit 8. Off Isolation



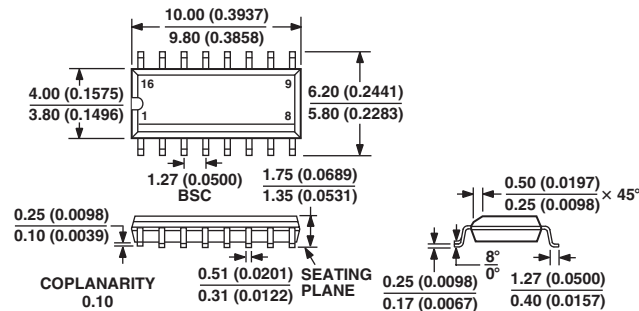
Test Circuit 9. Charge Injection



OUTLINE DIMENSIONS

16-Lead Standard Small Outline Package [SOIC]  
Narrow Body  
(R-16)

Dimensions shown in millimeters and (inches)

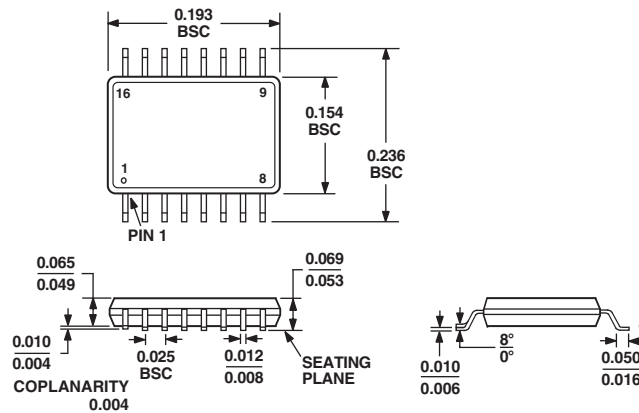


COMPLIANT TO JEDEC STANDARDS MS-012AC

CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN

16-Lead Shrink Small Outline Package [QSOP]  
(RQ-16)

Dimensions shown in inches



COMPLIANT TO JEDEC STANDARDS MO-137AB

## Revision History

| Location                                               | Page      |
|--------------------------------------------------------|-----------|
| <b>3/04—Data Sheet changed from REV. B to REV. C.</b>  |           |
| Added APPLICATIONS .....                               | 1         |
| Changes to ORDERING GUIDE .....                        | 4         |
| <b>10/03—Data Sheet changed from REV. A to REV. B.</b> |           |
| Updated formatting .....                               | Universal |
| Renumbered TPCs and Figures .....                      | Universal |
| Changes to FEATURES .....                              | 1         |
| Changes to APPLICATIONS .....                          | 1         |
| Changes to PRODUCT HIGHLIGHTS .....                    | 1         |
| Changes to SPECIFICATIONS .....                        | 2         |
| Changes to ABSOLUTE MAXIMUM RATINGS .....              | 4         |
| Updated ORDERING GUIDE .....                           | 4         |
| Delete Figure 2 .....                                  | 7         |
| Updated OUTLINE DIMENSIONS .....                       | 10        |
| <b>4/03—Data Sheet changed from REV. 0 to REV. A.</b>  |           |
| Renumbered TPCs and Figures .....                      | Universal |
| Updated OUTLINE DIMENSIONS .....                       | 8         |

